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Raman & Infrared Study of Bi Filled $\text{Co}_4\text{Sb}_{12}$

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Abstract. CoSb_3 skutterudites are established thermoelectric materials in the 500-800K temperature range. Undoped and Bi filled CoSb_3 samples were synthesized by induction melting-annealing process and phase confirmation done by X-Ray diffraction. The role of bismuth as a filler in CoSb_3 was investigated by Raman and far infrared reflectance study. It was found that bismuth strengthens Sb vibrations, and can potentially scatter Sb related acoustic phonons effectively. As a result substantial reduction in thermal conductivity may be possible with proper control of Bi filling.

Keywords: thermoelectric, induction melting, Raman, infrared, phonon

PACS: 72.20.Pa, 81.10.Fq, 78.30.Fs, 72.10.Di

INTRODUCTION

Thermoelectric materials convert thermal energy to electrical energy and vice-versa. The efficiency of this conversion depends on a dimensionless figure of merit $zT = (S^2\sigma/\kappa)T$, where S is Seebeck coefficient, σ is electrical conductivity and κ is the thermal conductivity. Good thermoelectric materials should have a high S & σ and low κ . CoSb_3 skutterudites are efficient thermoelectric generators having complex crystal structure, large unit cell and high carrier mobility. Large voids of radius 1.892\AA are present inside the center of the $\text{Co}_4\text{Sb}_{12}$ formula units. When these voids are filled by foreign atoms, filler atoms rattle inside the cage and scatter the heat carrying phonons. This large scattering of phonons decreases κ , thereby increasing the zT . The behavior of these vibration modes can be understood to some extent by Raman and Infrared spectroscopy. Here, polycrystalline $\text{Bi}_x\text{Co}_4\text{Sb}_{12}$ ($x=0, 0.25, 0.5$) has been synthesized and vibration modes studied by the above techniques.

EXPERIMENTAL PROCEDURE

High purity Co (99.995%), Sb (99.999%) and Bi (99.999%) were mixed in stoichiometric ratio and sealed in quartz ampoules under 10^{-4} torr vacuum. The samples were melted by induction heating at 1273 K for 15 min and then quenched in water, followed by annealing at 923 K for 144 hours. Phase identification was done by X-Ray Diffraction (Bruker D8 advance)

on powdered samples. Optical measurements were done at room temperature on polished samples. Raman data was acquired using HORIBA Jobin Yvon LabRAM HR800 spectrometer with Argon 514.5 nm visible laser. Sampling was carried out by standard optical microscope using MPlan N 100X objective. Infrared measurements were carried out on Bruker IFS 66v/s Vacuum Fourier Transform Interferometer in the FIR range.

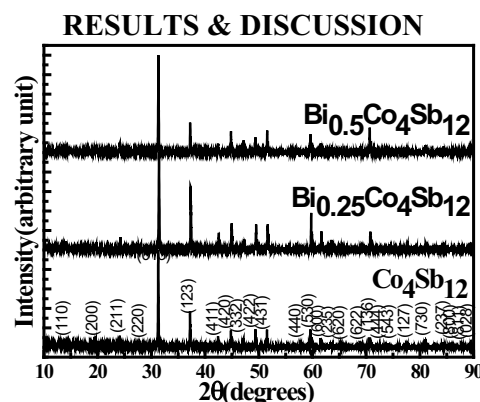


FIGURE1: XRD patterns of $\text{Bi}_x\text{Co}_4\text{Sb}_{12}$ ($x=0, 0.25, 0.5$)

CoSb_3 skutterudite phase is observed as the major phase in all samples. No secondary phases are observed in any of the samples. This indicates that Bi atom can easily be incorporated into CoSb_3 host lattice upto a filling limit of 0.5.

In CoSb_3 unit cell, out of four formula units, one formula unit is empty and other three consist of

TABLE 1. Phonon frequencies of CoSb₃(Raman& Infrared)

Raman Shift (cm ⁻¹) CoSb ₃	Theoretical (cm ⁻¹) ^[1]	Modes	FTIR (cm ⁻¹) CoSb ₃	Theoretical (cm ⁻¹) ^[3]	Modes
80.3	83.3	F _g	119	120	F _u
106.8	109.8	F _g	245	247	F _u
148.2	150.5	A _g	256	257	F _u
159.8	156.7	F _g	278	275	F _u
180.3	178.2	E _g			

four membered Sb rings in the centre. Hence, possible interactions are Co-Co, Sb-Sb or Co-Sb. The eight sensitive Raman modes for CoSb₃ skutterudite are 2A_g+2E_g+4F_g^[1]. The experimental data and theoretically calculated Raman shifts for CoSb₃ are given in Table(1). In Bi filled samples all the Raman peaks shift up a little as shown in fig 2. For Bi_{0.25}Co₄Sb₁₂ and Bi_{0.5}Co₄Sb₁₂ the first F_g mode is observed at 83.13 cm⁻¹ and 82.02 cm⁻¹ which is slightly shifted towards the higher frequency than that of unfilled Co₄Sb₁₂. Similar result has been reported for rare earth filled skutterudites^[2] where the filler atom has been shown to weaken some of the Sb vibrations as well as strengthen other Sb vibrations. The strengthening corresponds to up shift in Raman peaks while weakening to down shift. Up shift in Raman peaks in Bi filled Co₄Sb₁₂ indicates that Bi filler may strengthen the Sb vibration modes.

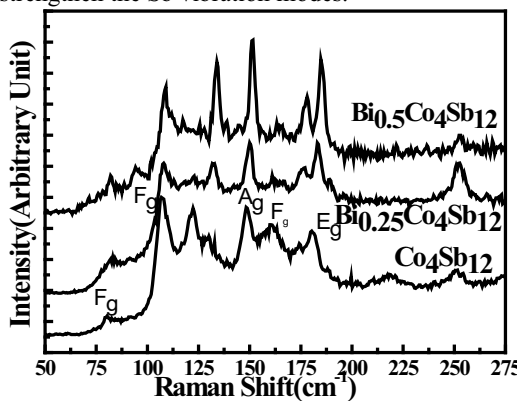


FIGURE 2. Raman spectra of Bi_xCo₄Sb₁₂ (x=0, 0.25, 0.5)

FTIR spectrum for all the samples is shown in figure (3). CoSb₃ showed poor reflectance as compared to the Bi filled samples. However, the peaks at 118.6, 245, 256 & 278 cm⁻¹ were identified as belonging to the F_u zone centre vibrations of the CoSb₃ crystal. Comparison with available literature data is given in Table (1). In addition to these, samples Bi_{0.25}Co₄Sb₁₂ and Bi_{0.5}Co₄Sb₁₂ showed peaks at 137, 186 and 415 cm⁻¹. These could possibly be due to Bi since it is a heavy element and is thus expected to give low frequency phonon vibration modes. Large κ reduction by scattering of Sb related phonons (50-175 cm⁻¹) has

been predicted^[3]. Since Bi vibrations fall in the above range, Bi can scatter phonons effectively.

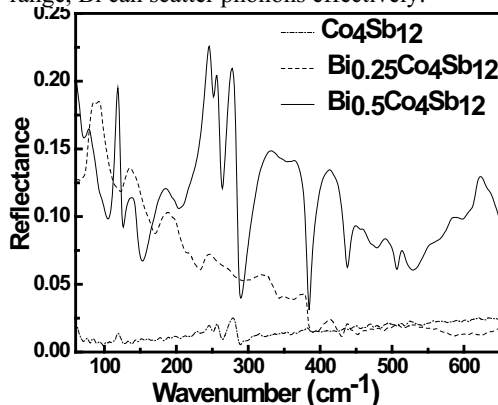


FIGURE 3 FTIR spectra of Bi_xCo₄Sb₁₂ (x=0, 0.25, 0.5)

CONCLUSIONS

Bi filled CoSb₃ skutterudites were prepared by induction heating process. Bi atom was found to be incorporated into the lattice for both the filling fractions of bismuth. Bi vibration modes were found to lie near Sb related phonon modes, thereby indicating it as effective scattering centre. The observed Raman shift confirmed that Bi vibration modes could strengthen the Sb vibrations. To investigate the role of Bi further as a filler atom, detailed theoretical study needs to be undertaken.

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